

100mA / 50V Digital transistors

(with built-in resistors)

DTC144GE / DTC144GUA / DTC144GKA

Applications

Inverter, Interface, Driver

Features

- 1)The built-in bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input, and parasitic effects are almost completely eliminated.
- 2)Only the on / off conditions need to be set for operation, making the device design easy.
- 3)Higher mounting densities can be achieved.

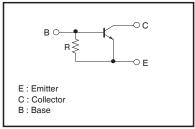
Structure

NPN epitaxial planar silicon transistor (Resistor built-in type)

Packaging specifications

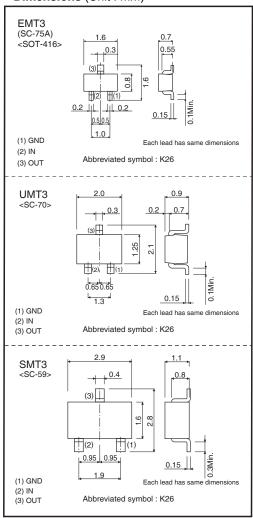
| | Package | EMT3 | UMT3 | SMT3 |
|-----------|------------------------------|--------|--------|--------|
| | Packaging type | Taping | Taping | Taping |
| | Code | TL | T106 | T146 |
| Part No. | Basic ordering unit (pieces) | 3000 | 3000 | 3000 |
| DTC144GE | | 0 | _ | _ |
| DTC144GUA | | _ | 0 | _ |
| DTC144GKA | | _ | _ | 0 |

Inner circuit



R=47kΩ

• Dimensions (Unit : mm)



Absolute maximum ratings (Ta=25°C)

| Parameter | | Symbol | Limits | Unit | |
|-----------------------------|-----------------------|--------|-------------|-------|--|
| Collector-base voltage | | Vсво | 50 | V | |
| Collector-emitter voltage | | VCEO | 50 | V | |
| Emitter-base voltage | | VEBO | 5 | V | |
| Collector current | | Ic | 100 | mA | |
| Collector power dissipation | DTC144GE | Pc | 150 | mW | |
| | DTC144GUA / DTC144GKA | PC | 200 | IIIVV | |
| Junction temperature | | Tj | 150 | °C | |
| Storage temperature | | Tstg | -55 to +150 | °C | |

• Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|--------------------------------------|--------------|------|------|------|------|--------------------------------|
| Collector-base breakdown voltage | ВУсво | 50 | - | - | V | Ic=50μA |
| Collector-emitter breakdown voltage | BVceo | 50 | - | _ | V | Ic=1mA |
| Emitter-base breakdown voltage | ВУево | 5 | - | - | V | Iε=160μA |
| Collector cutoff current | Ісво | _ | - | 0.5 | μΑ | Vcb=50V |
| Emitter cutoff current | ІЕВО | 65 | _ | 130 | μΑ | V _{EB} =4V |
| Collector-emitter saturation voltage | VCE(sat) | _ | _ | 0.3 | V | Ic=10mA, I _B =0.5mA |
| DC current transfer ratio | hfe | 68 | - | - | _ | Ic=5mA , VcE=5V |
| Emitter-base resistance | R | 32.9 | 47 | 61.1 | kΩ | _ |
| Transition frequency | f ⊤ * | _ | 250 | - | MHz | Vc=10V , I=-5mA , f=100MHz |

^{*} Characteristics of built-in transistor

• Electrical characteristics curves

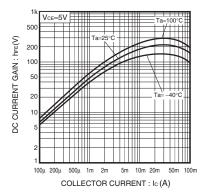


Fig.1 DC current gain vs. Collector current

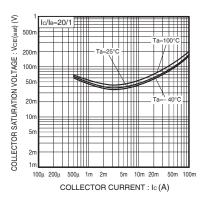


Fig.2 Collector-Emitter saturation vs. Collector current

Notes

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